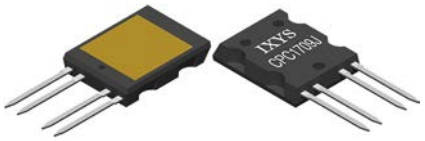
CPC1709J

60V, 22.8 A, Single-Pole Normally Open DC-Only Power Relay



Characteristics

Parameter	Rating	Units
Blocking Voltage	60	V_P
Load Current, T_A=25°C:		
With 5°C/W Heat Sink	22.8	A_{DC}
No Heat Sink	9	A_{DC}
On-Resistance (max)	0.05	Ω
Thermal Impedance, Junction-to-Case, θ_{JC}	0.3	°C/W

Features

- 22.8A_{DC} Load Current with 5°C/W Heat Sink
- Low 0.05Ω On-Resistance
- 60V_P Blocking Voltage
- 2500V_{rms} Input/Output Isolation
- Low Thermal Impedance: θ_{JC} = 0.3 °C/W
- Isolated, Low Thermal Impedance Ceramic Pad for Heat Sink Applications
- Low Drive Power Requirements
- No EMI/RFI Generation
- Flammability Rating UL 94 V-0

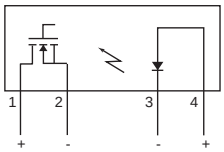
Applications

- Industrial Controls / Motor Control
- Robotics
- Medical Equipment—Patient/Equipment Isolation
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Transportation Equipment

Approvals

- UL 508 Certified Component: File E69938

Pin Configuration



Description

IXYS Integrated Circuits brings OptoMOS® technology, reliability and compact size to a new family of high-power Solid State Relays.

As part of this family, the CPC1709J single-pole normally open (1-Form-A) DC Solid State Power Relay employs optically coupled MOSFET technology to provide 2500V_{rms} of input to output isolation.

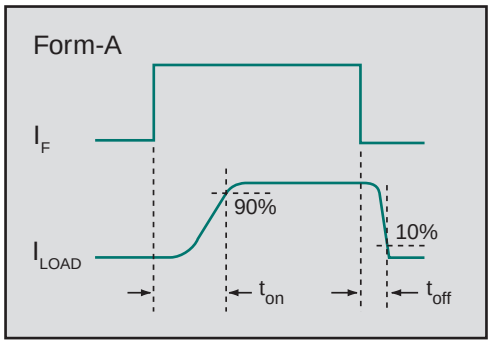
The output, constructed with an efficient MOSFET switch and photovoltaic die, uses IXYS Integrated Circuits' patented OptoMOS architecture while the input, a highly efficient infrared LED, provides the optically coupled control. The combination of low on-resistance and high load current handling capability makes this relay suitable for a variety of high performance DC switching applications.

The unique ISOPLUS-264 package pioneered by IXYS enables Solid State Relays to achieve the highest load current and power ratings. This package features a unique IXYS process where the silicon chips are soft soldered onto the Direct Copper Bond (DCB) substrate instead of the traditional copper leadframe. The DCB ceramic, the same substrate used in high power modules, not only provides 2500V_{rms} isolation but also very low junction-to-case thermal impedance (0.3 °C/W).

Ordering Information

Part	Description
CPC1709J	ISOPLUS-264 Package (25 per tube)

Switching Characteristics



1 Specifications

1.1 Absolute Maximum Ratings @ 25°C

Parameter	Symbol	Rating	Unit
Blocking Voltage	V_L	60	V_P
Reverse Input Voltage	V_R	5	V
Input Control Current, Continuous	I_F	100	mA
Peak (10ms)		1	A
Input Power Dissipation	P_{IN}	150	mW
Isolation Voltage (Input to Output)	V_{ISO}	2500	V_{rms}
Operating Temperature, Ambient	T_A	-40 to +85	°C
Storage Temperature	T_{STG}	-40 to +125	°C

Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Typical values are characteristic of the device at +25°C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.

1.2 Electrical Characteristics @ 25°C

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Output Characteristics						
Blocking Voltage	I_L=1µA	V_{DRM}	60	-	-	V
Load Current [1]						
Peak	t≤10ms	I_L	-	-	40	A_P
Continuous	No Heat Sink				9	A_{DC}
Continuous	T_C=25°C				32	
Continuous	T_C=99°C	$I_{L(99)}$			11	
On-Resistance [2]	I_F=10mA, I_L=1A	R_{ON}	-	0.027	0.05	Ω
Off-State Leakage Current	V_L=60V_P	I_{LEAK}	-	-	1	µA
Switching Speeds						
Turn-On	I_F=20mA, V_L=10V	t_{on}	-	7	20	ms
Turn-Off		t_{off}	-	0.22	5	
Output Capacitance	I_F=0mA, V_L=25V, f=1MHz	C_{out}	-	4000	-	pF
Input Characteristics						
Input Control Current to Activate [3]	I_L=1A	I_F	-	-	10	mA
Input Dropout Current to Deactivate	-	I_F	0.6	-	-	mA
Input Voltage Drop	I_F=10mA	V_F	0.9	1.42	1.56	V
Reverse Input Current	V_R=5V	I_R	-	-	10	µA
Input/Output Characteristics						
Capacitance, Input-to-Output	V_{IO}=0V, f=1MHz	C_{IO}	-	1	-	pF

[1] Higher load currents possible with proper heat sinking.

[2] Measurement taken within 1 second of on-time.

[3] For applications requiring high temperature operation (> 60ºC) a minimum LED drive current of 20mA is recommended.

2 Thermal Characteristics

Parameter	Conditions	Symbol	Rating	Units
Thermal Impedance (Junction to Case)	-	θ_{JC}	0.3	°C/W
Thermal Impedance (Junction to Ambient)	Free Air	θ_{JA}	33	°C/W
Junction Temperature (Operating)	-	T_J	-40 to +100	°C

2.1 Thermal Management

Device high current characterization was performed using Kunze heat sink KU 1-159, phase change thermal interface material KU-ALC 5, and transistor clip KU 4-499/1. This combination provided an approximate junction-to-ambient thermal impedance of 12.5°C/W.

2.2 Heat Sink Calculation

Higher load currents are possible by using lower thermal impedance heat sink combinations.

Heat Sink Rating

$$\theta_{CA} = \frac{(T_J - T_A)\, I_{L(99)}^2}{I_L^2 \bullet P_{D(99)}} - \theta_{JC}$$

T_J = Junction Temperature (°C), $T_J \leq 100°C$ *
T_A = Ambient Temperature (°C)
$I_{L(99)}$ = Load Current with Case Temperature @ 99°C (A_{DC})
I_L = Desired Operating Load Current (A_{DC}), $I_L \leq I_{L(MAX)}$
θ_{JC} = Thermal Impedance, Junction to Case (°C/W) = 0.3°C/W
θ_{CA} = Thermal Impedance of Heat Sink & Thermal Interface Material , Case to Ambient (°C/W)
$P_{D(99)}$ = Maximum power dissipation with case temperature held at 99ºC = 3.33W

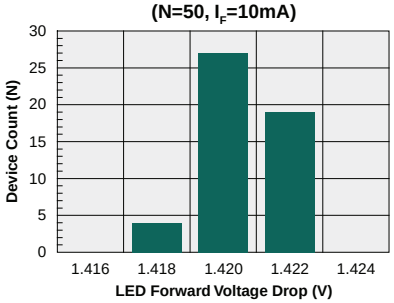
* Elevated junction temperature reduces semiconductor lifetime.

NOTE: The exposed surface of the DCB substrate is not to be soldered.

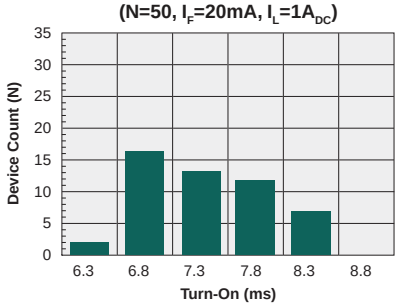
3 Performance Data*

Unless otherwise specified, all performance data was acquired without the use of a heat sink.

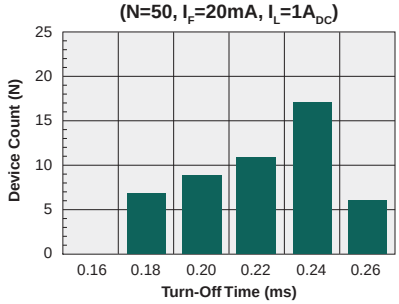
Typical LED Forward Voltage Drop (N=50, I_F=10mA)



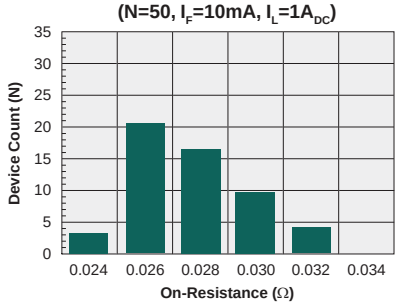
Typical Turn-On Time (N=50, I_F=20mA, I_L=1A_{DC})



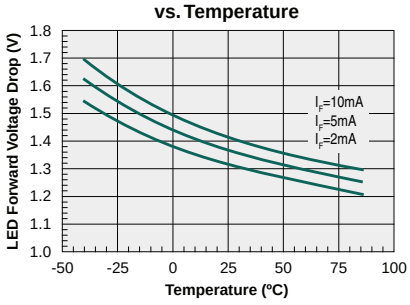
Typical Turn-Off Time (N=50, I_F=20mA, I_L=1A_{DC})



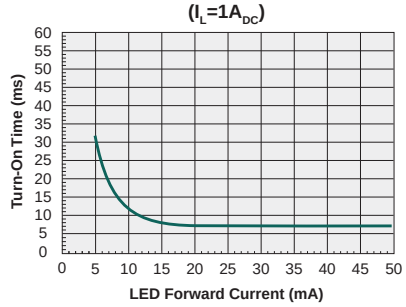
Typical On-Resistance Distribution (N=50, I_F=10mA, I_L=1A_{DC})



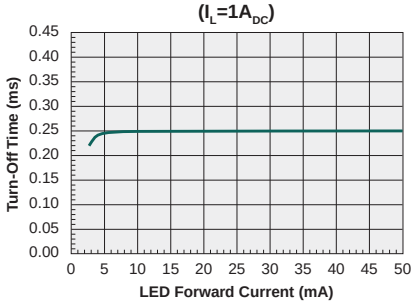
Typical LED Forward Voltage Drop vs. Temperature



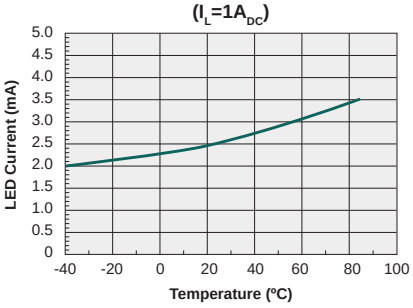
Typical Turn-On Time vs. LED Forward Current (I_L=1A_{DC})



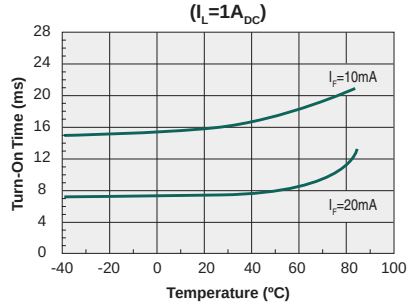
Typical Turn-Off Time vs. LED Forward Current (I_L=1A_{DC})



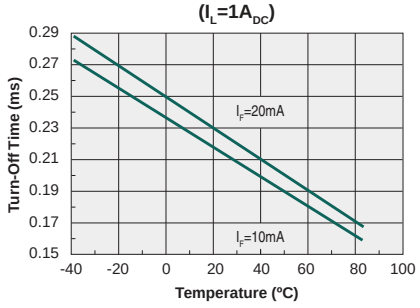
Typical I_F for Switch Operation vs. Temperature (I_L=1A_{DC})



Typical Turn-On Time vs. Temperature (I_L=1A_{DC})

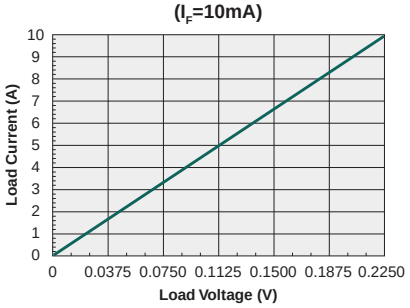


Typical Turn-Off Time vs. Temperature (I_L=1A_{DC})

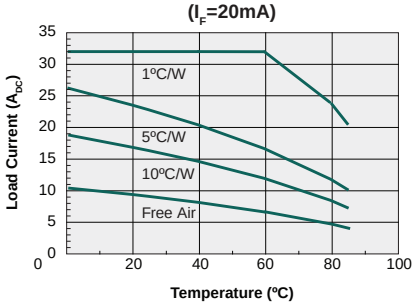


* Unless otherwise noted, data presented in these graphs is typical of device operation at 25ºC.

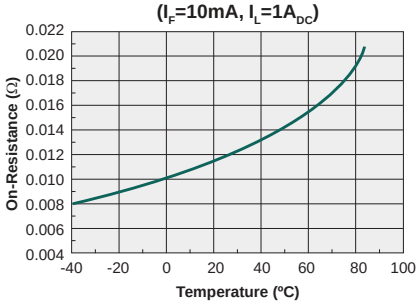
Typical Load Current vs. Load Voltage (I_F=10mA)



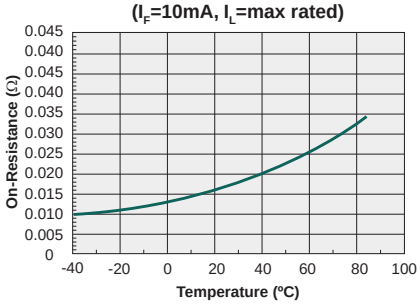
Maximum Load Current vs. Temperature with Heat Sink (I_F=20mA)



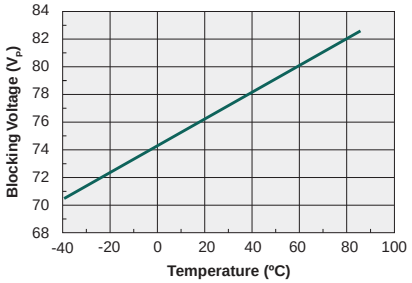
Typical On-Resistance vs. Temperature (I_F=10mA, I_L=1A_{DC})



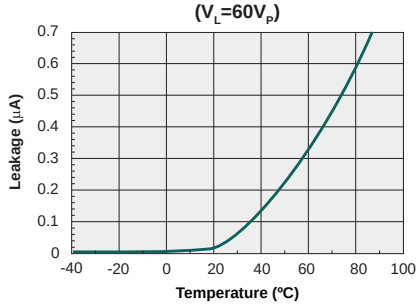
Typical On-Resistance vs. Temperature (I_F=10mA, I_L=max rated)



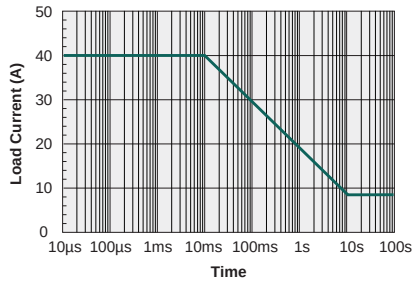
Normalized Blocking Voltage vs. Temperature



Typical Leakage vs. Temperature Measured Across Pins 1&2 (V_L=60V_P)



Energy Rating Curve Free Air, No Heat Sink



* Unless otherwise noted, data presented in these graphs is typical of device operation at 25ºC.

4 Manufacturing Information

4.1 ESD Sensitivity

This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

4.2 Soldering Profile

For through-hole devices, the maximum pin temperature and maximum dwell time through all solder waves is provided in the table below. Dwell time is the interval beginning when the pins are initially immersed into the solder wave until they exit the solder wave. For multiple waves, the dwell time is from entering the first wave until exiting the last wave. During this time, pin temperatures must not exceed the maximum temperature given in the table below. Body temperature of the device must not exceed the limit shown in the table below at any time during the soldering process.

Device	Maximum Pin Temperature	Maximum Body Temperature	Maximum Dwell Time	Wave Cycles
CPC1709J	260°C	245°C	10 seconds*	1

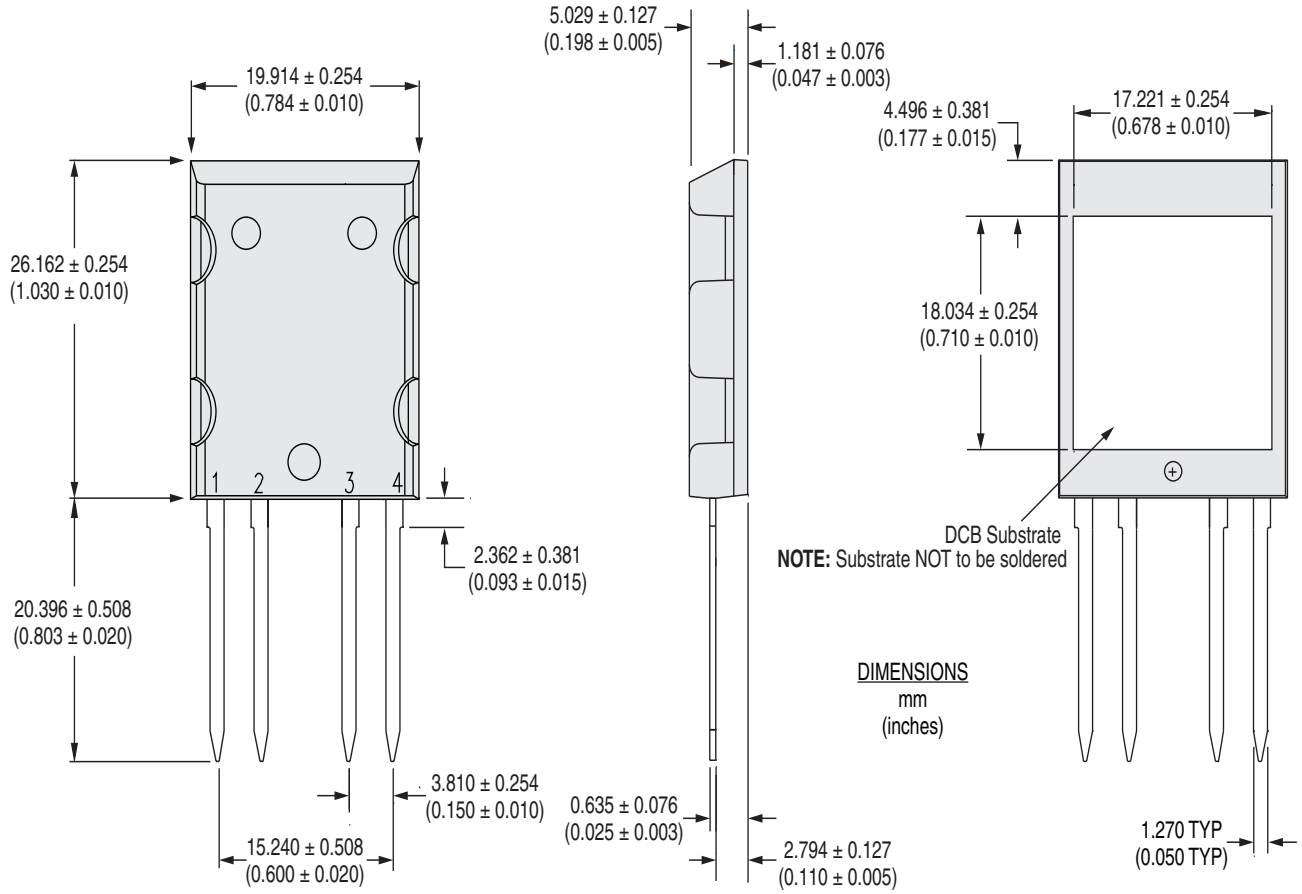
*Total cumulative duration of all waves.

NOTE: The exposed surface of the DCB substrate must not be soldered.

4.3 Board Wash

IXYS Integrated Circuits recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

4.4 Mechanical Dimensions



NOTES:
1. Controlling dimension: Inches.
2. Metallized external surface of DCB substrate maintains 2500V_{rms} isolation to device internal structure and all external pins.

For additional information please visit our website at: https://www.ixysic.com

IXYS A Littelfuse Technology

Specification: DS-CPC1709J-R11

10/25/2021